| Reg. No   | ••  |  |
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## DIPLOMA EXAMINATION IN ENGINEERING/TECHNOLOGY/ MANAGEMENT/COMMERCIAL PRACTICE, APRIL – 2023

# **BASIC ELECTRONICS**

[Maximum Marks: 75]

[Time: 3 Hours]

### PART-A

I. Answer all the following questions in one word or one sentence. Each question carries 'one' mark.
(9 x 1 = 9 Marks)

|    |  | $(9 \times 1 = 9)$ | , |
|----|--|--------------------|---|
|    |  | Module Outcome     |   |
| 1. | Define doping.   | M1.01              | R |
| 2. | Draw the V-I characteristics of PN junction diode.   | M1.03              | R |
| 3. | List the modes of operation of transistor.   | M2.02              | R |
| 4. | State the relationship between $\alpha$ and $\beta$ .  | M2.03              | R |
| 5. | <sup>۲</sup>   | M2.01              | R |
|    | B<br>E   |                    |   |
|    | Identify the component.  |                    |   |
| 6. | Draw the equivalent circuit of UJT.  | M3.01              | R |
| 7. | Define intrinsic standoff ratio.   | M3.02              | R |
| 8. | List any two non-linear wave shaping circuits.   | M4.04              | R |
| 9. | Name the output waveform obtained, when a square wave is given as input to the integrator circuit. | M4.03              | R |

#### PART-B

### II. Answer any *eight* questions from the following. Each question carries 'three' marks.

(8 x 3 = 24 Marks) Module Outcome Cognitive level

|    |   | Module Outcome | Cognitive level |
|----|---|----------------|-----------------|
| 1. | List and define any three specifications of diode.  | M1.04          | R               |
| 2. | Explain the drift current and diffusion current of diode.   | M1.02          | U               |
| 3. | "CE configuration is most widely used in amplifier circuits". Justify the statement.  | M2.04          | U               |
| 4. | Explain the basic conditions that must be satisfied for the faithful amplification.   | M2.05          | U               |
| 5. | <ul> <li>a) Classify the voltage that should be applied for the operations of N channel JFET. (2 marks)</li> <li>b) Interpret the operation of N channel JFET when no voltage is applied. (1 mark)</li> </ul> | M3.02          | U               |
| 6. | Draw the energy band diagram of semiconductors.   | M1.01          | R               |
| 7. | Define static and dynamic forward resistances of PN junction diode.   | M1.03          | R               |

| 8.  | What are the values of TUF, ripple factor and DC output voltage              | M4.01 | R |
|-----|--|-------|---|
|     | having a peak voltage of 10V in a half wave rectifier circuit.               |       |   |
| 9.  | Explain the effect of temperature in leakage current.                        | M2.03 | U |
| 10. | Explain the biasing conditions for various modes of operation of transistor. | M2.02 | U |

# PART-C Answer all questions. Each question carries *'seven'* marks

|       |   | $(6 \times 7 = 42)$<br>Module Outcome |   |
|-------|---|---------------------------------------|---|
| III.  | Compare P-type and N-type semiconductors.                           | M1.01                                 | U |
|       | OR  |                                       |   |
| IV.   | Classify and explain various biasing conditions of p-n junction.    | M1.03                                 | U |
| V.    | Compare the three transistor configurations.                        | M2.04                                 | U |
|       | OR  |                                       |   |
| VI.   | Describe the physical structure of BJT with diagram.                | M2.01                                 | U |
| VII.  | Describe the physical structure of MOSFET with diagram.             | M3.01                                 | U |
|       | OR  |                                       |   |
| VIII. | With neat sketch explain the ON state of UJT.                       | M3.02                                 | U |
|       |   |                                       |   |
| IX.   | Design and illustrate the operation of an RC integrator with square | M4.03                                 | А |
|       | wave signal.  |                                       |   |
|       | OR  |                                       |   |
| Χ.    | Construct and explain the operation of double slicer at +2V and     | M4.04                                 | А |
|       | -2V. Sketch the input –output waveforms. (Assume ideal diode        |                                       |   |
|       | conditions).  |                                       |   |
| XI.   | With diagram explain the working of series inductor filter.         | M4.02                                 | U |
|       | OR  |                                       |   |
| XII.  | Explain the working of half wave voltage doubler with diagram.      | M4.05                                 | U |
| XIII. | Draw and describe the structure of UJT.                             | M3.01                                 | U |
|       | OR  |                                       |   |
| XIV.  | A) Draw the symbol for N channel JFET. (2 marks)                    | M3.01                                 | R |
|       | B) Draw the drain and transfer characteristics of                   | M3.03                                 | R |
|       | JFET. (5 marks)   |                                       |   |

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